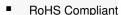


April 2013

# FDZ1040L Integrated Load Switch

#### **Features**

- Optimized for Low-Voltage Core ICs in Portable Systems
- Very Small Package Dimension: WLCSP 0.8 X 0.8 X 0.5 mm<sup>3</sup>
- Current = 1.2 A, VIN max = 4 V
- Current = 2 A, VIN max = 4 V (Pulsed)
- $R_{DS(on)} = 80 \text{ m}\Omega \text{ at } V_{ON} = V_{IN} = 4 \text{ V}$
- $R_{DS(on)} = 90 \text{ m}\Omega \text{ at } V_{ON} = V_{IN} = 3 \text{ V}$
- $\blacksquare$  R<sub>DS(on)</sub> = 110 mΩ at V<sub>ON</sub> = 0.7 V, V<sub>IN</sub> = 1.6 V
- R<sub>DS(on)</sub> = 309 mΩ at  $V_{ON}$  = 0.7 V,  $V_{IN}$  = 1 V





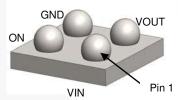


Figure 1. Bottom View

## **Description**

This device is particularly suited for compact power management in portable applications needing 1 V to 4 V input and 1.2 A output current capability. This load switch integrated a level-shifting function that drives a P-channel power MOSFET in a very small 0.8 X 0.8 X 0.5 mm<sup>3</sup> WLCSP package.

## **Applications**

- Load Switch
- Power Management in Portable Applications



Figure 2. Top View

## **Ordering Information**

Part Number	Device Mark	Ball Pitch	Operating Temperature Range	Switch	Package	Packing Method
FDZ1040L	ZL	0.4 mm	-40 to 85°C	80 m, P-Channel MOSFET	0.8 x 0.8 x 0.5 mm <sup>3</sup> WLCSP	Tape & Reel

## **Typical Application**

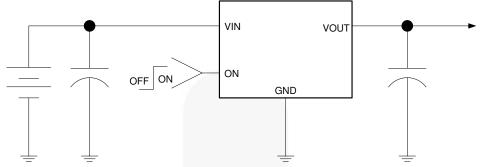


Figure 3. Typical Application

## **Block Diagram**

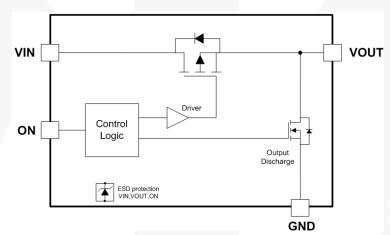


Figure 4. Internal Block Diagram

# **Pin Configuration**



Figure 5. Top View (Bumps Down) Figure 6. Bottom View (Bumps Up)

## **Pin Descriptions**

Pin#	Name	Description	
A1	VIN	Supply Input: Input to the load switch	
A2	VOUT	vitch Output: Output of the load switch	
B1	ON	N/OFF Control Input, Active High	
B2	GND	round	

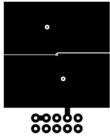
### **Absolute Maximum Ratings**

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

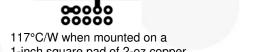
Symbol	Parameter			Max.	Unit
$V_{IN}$	Voltage on VIN, VOUT, ON to GNE		-0.3	4.2	V
I <sub>OUT_C</sub>	I <sub>OUT</sub> -Load Current (Continuous) <sup>(1a)</sup>			1.2	Α
I <sub>OUT_P</sub>	I <sub>OUT</sub> -Load Current (Pulsed)			2	Α
P <sub>D</sub>	Power Dissipation at T <sub>A</sub> = 25°C <sup>(1a)</sup>			0.9	W
T <sub>A</sub>	Operating Temperature Range			85	°C
T <sub>STG</sub>	Storage Temperature			150	°C
$R_{\Theta_{JA}}$	Thermal Resistance, Junction to Ambient <sup>(1a)</sup>			135	°C/W
ESD	Floatus atatia Disabaura Canability	Human Body Model, JESD22-A114	8		kV
	Electrostatic Discharge Capability  Charged Device Model, JESD22-C101		2		K.V

#### Notes:

RO<sub>JA</sub> is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. RO<sub>JC</sub> is guaranteed by design, while RO<sub>JA</sub> is determined by the board design.



117°C/W when mounted on a 1-inch square pad of 2-oz copper.





277°C/W when mounted on a minimum pad of 2-oz copper.

Pulse test: pulse width  $< 300 \mu s$ ; duty cycle < 2.0%.

## **Recommended Operating Conditions**

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. Fairchild does not recommend exceeding them or designing to Absolute Maximum Ratings.

Symbol	Parameter		Max.	Unit
V <sub>IN</sub>	Voltage on VIN Pin		4	V
V <sub>ON</sub>	Voltage on ON Pin		4.0	V
T <sub>A</sub>	Operating Temperature Range		85	°C

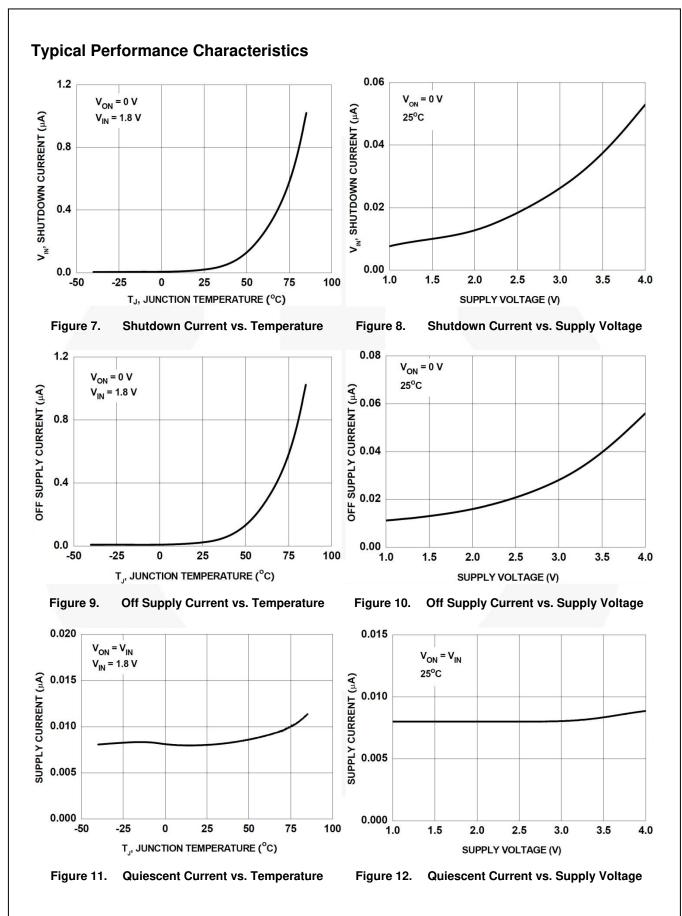
## **Electrical Characteristics**

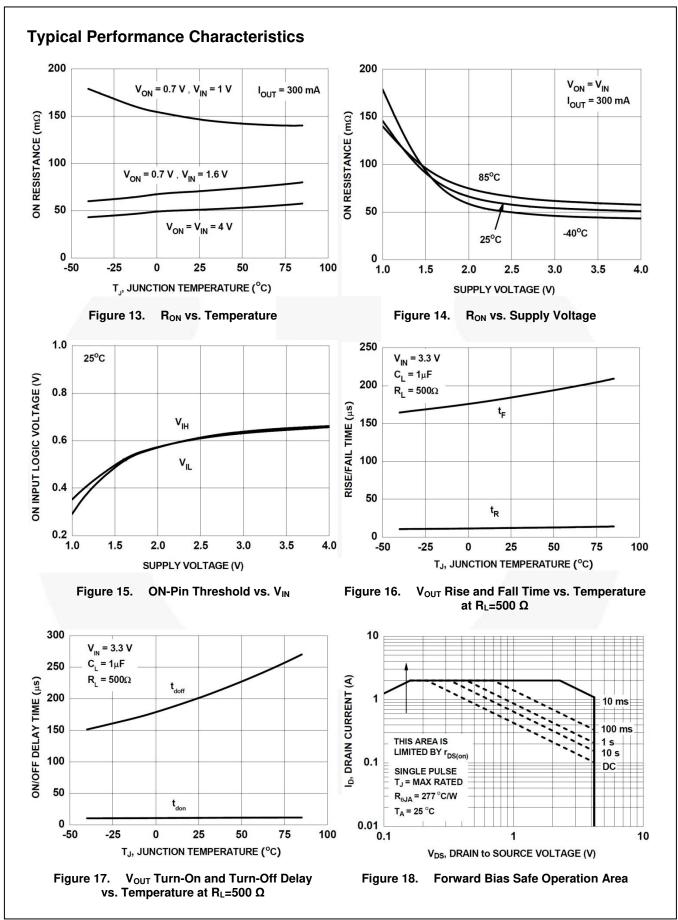
 $T_J = 25$ °C unless otherwise noted.

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
V <sub>IN</sub>	Operation Voltage				4	٧
	ON logget Logic Loggy Voltage	1.6 V ≤ V <sub>IN</sub> ≤ 4 V			0.35	V
V <sub>IL</sub>	ON Input Logic Low Voltage	1 V ≤ V <sub>IN</sub> ≤ 1.6 V			0.25	
V	ON Input Logic High Voltage	$1.6 \text{ V} \leq \text{V}_{\text{IN}} \leq 4 \text{ V}$	1.0			V
V <sub>IH</sub>	ON Input Logic High Voltage	$1 \text{ V} \leq \text{V}_{\text{IN}} \leq 1.6 \text{ V}$	0.7			
ΙQ	Quiescent Current	$V_{IN} = V_{ON} = 1.8 \text{ V}, V_{OUT} = \text{Float}$			1	μΑ
$I_{Q(off)}$	Off Supply Current $V_{IN} = 1.8 \text{ V}, V_{ON} = \text{GND}, V_{OUT}$				1	μΑ
I <sub>SD(off)</sub>	Off Switch Leakage Current	$V_{IN} = 1.8 \text{ V}, V_{ON} = GND, V_{OUT} = 0 \text{ V}$			100	nA
$R_{PD}$	Output Discharge Pull-Down Resistance			200		Ω
I <sub>ON</sub>	ON Input Leakage	V <sub>ON</sub> = V <sub>IN</sub> or GND			1	μA
7		$V_{ON} = V_{IN} = 4 \text{ V}, I_{OUT} = 300 \text{ mA}$		48	80	
		$V_{ON} = V_{IN} = 3.6 \text{ V}, I_{OUT} = 300 \text{ mA}$		49	85	
R <sub>DS(ON)</sub>	Static Drain-Source On-Resistance	$V_{ON} = V_{IN} = 3 \text{ V}, I_{OUT} = 300 \text{ mA}$		51	90	0
		$V_{ON} = 0.7 \text{ V}, V_{IN} = 1.6 \text{ V}, I_{OUT} = 300 \text{ mA}$		70	110	mΩ
		$V_{ON} = 0.7 \text{ V}, V_{IN} = 1 \text{ V}, I_{OUT} = 300 \text{ mA}$		142	309	
	y 1	$V_{IN} = 3.6 \text{ V}, I_{OUT} = 300 \text{ mA}, T_J = 85^{\circ}\text{C}$		59	120	

# **Switching Characteristics**

Symbol	Parameter	Test Conditions	Typical	Unit
$t_{d(on)}$	Turn-On Delay		22	μs
t <sub>r</sub>	Turn-On Rise Time	V 16VV 07V C 1::E B 500 C	23	μs
t <sub>d(off)</sub>	Turn-Off Delay	$V_{IN} = 1.6 \text{ V}, V_{ON} = 0.7 \text{ V}, C_L = 1  \mu\text{F}, R_L = 500  \Omega$	127	μs
t <sub>f</sub>	Turn-Off Fall Time		298	μs
t <sub>d(on)</sub>	Turn-On Delay		37	μs
tr	Turn-On Rise Time	V 1VV 18VC 10E B 500 O	35	μs
t <sub>d(off)</sub>	Turn-Off Delay	$V_{IN} = 1 \text{ V}, V_{ON} = 1.8 \text{ V}, C_L = 1 \mu\text{F}, R_L = 500 \Omega$	161	μs
t <sub>f</sub>	Turn-Off Fall Time		544	μs
t <sub>d(on)</sub>	Turn-On Delay		20	μs
t <sub>r</sub>	Turn-On Rise Time	$V_{IN} = 1.8 \text{ V}, V_{ON} = 1.8 \text{ V}, C_{I} = 1  \mu\text{F}, R_{I} = 500  \Omega$	22	μs
$t_{\text{d(off)}}$	Turn-Off Delay	$V_{IN} = 1.0 \text{ V}, V_{ON} = 1.0 \text{ V}, G_L = 1  \mu\text{F}, R_L = 300 \Omega$	136	μs
$t_f$	Turn-Off Fall Time		272	μs
$t_{d(on)}$	Turn-On Delay		15	μs
t <sub>r</sub>	Turn-On Rise Time	V 25 V V 18 V C 1 UF D 500 O	20	μs
t <sub>d(off)</sub>	Turn-Off Delay	$V_{IN} = 2.5 \text{ V}, V_{ON} = 1.8 \text{ V}, C_L = 1  \mu\text{F}, R_L = 500  \Omega$	168	μs
t <sub>f</sub>	Turn-Off Fall Time		229	μs
t <sub>d(on)</sub>	Turn-On Delay		13	μs
t <sub>r</sub>	Turn-On Rise Time	$V_{IN} = 3.3 \text{ V}, V_{ON} = 1.8 \text{ V}, C_L = 1  \mu\text{F}, R_L = 500  \Omega$	19	μs
t <sub>d(off)</sub>	Turn-Off Delay	$v_{IN} = 3.3 \text{ v}, v_{ON} = 1.0 \text{ v}, G_L = 1 \mu \text{r}, R_L = 500 \Omega$	202	μs
t <sub>f</sub>	Turn-Off Fall Time		214	μs







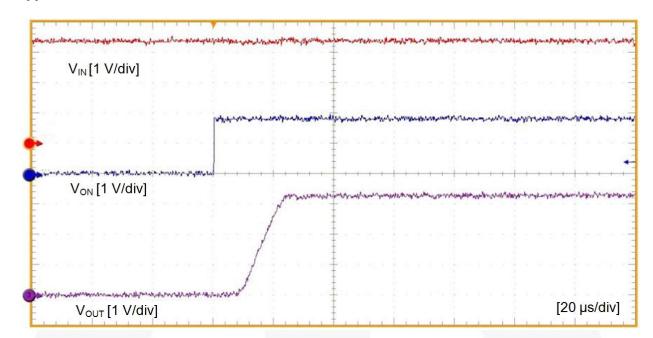


Figure 19. Turn-On Response ( $V_{IN}$  = 3.3 V,  $C_{OUT}$ =1  $\mu$ F,  $R_L$ =500  $\Omega$ )

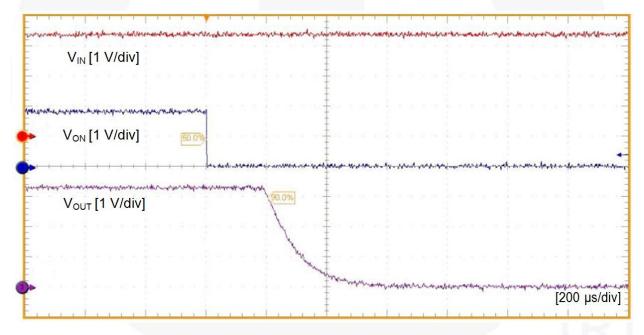


Figure 20. Turn-Off Response ( $V_{IN}$  = 3.3 V,  $C_{OUT}$ =1  $\mu$ F,  $R_L$ =500  $\Omega$ )

#### **Functional Description**

The FDZ1040L is a low- $R_{DS(ON)}$  P-channel load switch packaged in space-saving 0.8x0.8 WLCSP.

The core of the device is a  $80~\text{m}\Omega$  P-channel MOSFET capable of functioning over a wide input operating range

of 1-4 V. The ON pin, an active HIGH TTL-compatible input that supports input as low as 0.7 V, controls the state of the switch.

## **Applications Information**

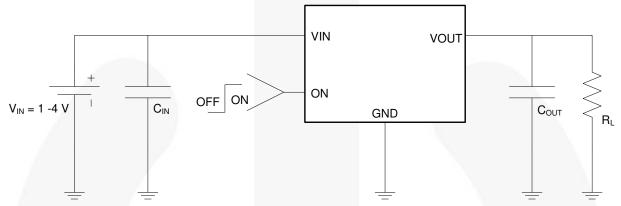


Figure 21. Typical Application

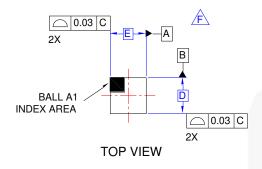
#### **Input Capacitor**

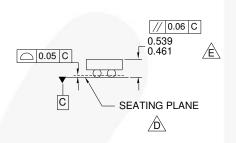
To reduce device inrush current effect, a 0.1  $\mu$ F ceramic capacitor,  $C_{IN}$ , is recommended close to the VIN pin. A higher value of  $C_{IN}$  can be used to further reduce the voltage drop experienced as the switch is turned on into a large capacitive load.

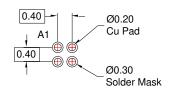
### **Output Capacitor**

FDZ1040L works without an output capacitor. However, if parasitic board inductance forces  $V_{\text{OUT}}$  below GND when switching off, a 0.1  $\mu\text{F}$  capacitor,  $C_{\text{OUT}}$ , should be placed between the VOUT and GND pins.

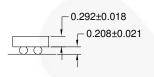
## **Physical Dimensions**







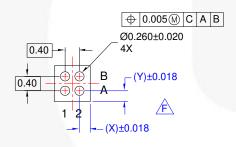
# RECOMMENDED LAND PATTERN (NSMD PAD TYPE)



SIDE VIEWS

#### NOTES:

- A. NO JEDEC REGISTRATION APPLIES.
- B. DIMENSIONS ARE IN MILLIMETERS.
- C. DIMENSIONS AND TOLERANCE PER ASME Y14.5M, 1994.
- DATUM C IS DEFINED BY THE SPHERICAL CROWNS OF THE BALLS.
- E.PACKAGE NOMINAL HEIGHT IS 500 MICRONS ±39 MICRONS (461-539 MICRONS).
- FOR DIMENSIONS D, E, X, AND Y SEE PRODUCT DATASHEET.
- G. DRAWING FILNAME: MKT-UC004AFrev1.



**BOTTOM VIEW** 

#### Figure 22. 4-Ball, WLCSP, 2 X 2 Array, 0.4 mm Pitch, 250 µm Ball

#### **Product-Specific Dimensions**

Product	D	E	X	Υ	
FDZ1040L 0.8 ±0.03 mm		0.8 ±0.03 mm	0.21 mm	0.21 mm	

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